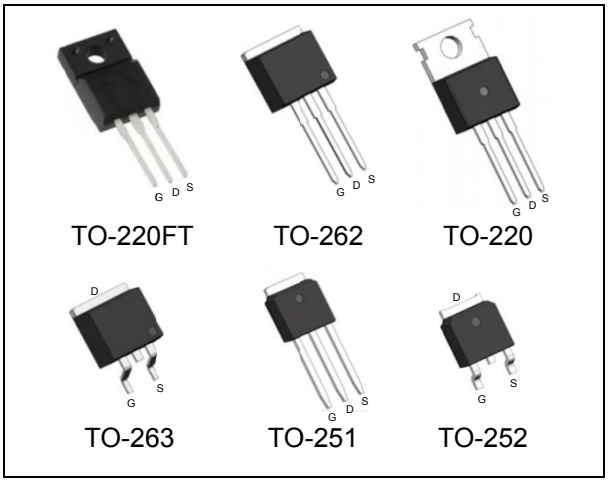
650V 0.96Ω Super Junction Power MOSFET

Description

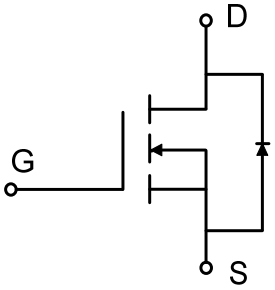
WMOS™ C4 is Wayon's 4th generation super junction MOSFET family that is utilizing charge balance technology for extremely low on-resistance and low gate charge performance. WMOS™ C4 is suitable for applications which require superior power density and outstanding efficiency.



Features

- V_{DS} =700V @ $T_{j,max}$
- Typ. $R_{DS(on)}$ =0.96Ω
- 100% UIS tested
- Pb-free plating, Halogen free

RoHS compliant



Applications

LED Lighting, Charger, Adapter, PC, LCD TV, Server

Absolute Maximum Ratings

Parameter	Symbol	WMK/WMM/WMN/WMP/WMO	WML	Unit
Drain-source voltage	V_{DSS}	650		V
Continuous drain current[1] (T_C = 25°C)	I_D	5		A
(T_C = 100°C)		2.8		A
Pulsed drain current[2]	I_{DM}	9		A
Gate-source voltage	V_{GS}	±30		V
Avalanche energy, single pulse[3]	E_{AS}	15		mJ
Avalanche energy, repetitive[2]	E_{AR}	0.1		mJ
Avalanche current, repetitive[2]	I_{AR}	0.7		A
Power dissipation (T_C = 25°C)	P_D	42	23	W
- Derate above 25°C		0.34	0.18	W/°C
Operating and storage temperature range	T_j, T_{stg}	-55 to +150		°C
Continuous diode forward current	I_S	5		A
Diode pulse current	$I_{S,pulse}$	9		A

Thermal Characteristics

Parameter	Symbol	WMK/WMM/WMN/WMP/WMO	WML	Unit
Thermal resistance, junction-to-case	$R_{\theta JC}$	3	5.4	°C/W
Thermal resistance, junction-to-ambient	$R_{\theta JA}$	62	80	°C/W

Electrical Characteristics T_c = 25°C, unless otherwise noted

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static characteristics						
Drain-source breakdown voltage	BV_{DSS}	V_{GS}=0 V, I_D=0.25 mA	650	-	-	V
Gate threshold voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=0.25mA	2	3	4	V
Drain cut-off current	I_{DSS}	V_{DS}=650 V, V_{GS}=0V, T_j = 25°C T_j = 125°C	 - -	 - 30	 1 -	μA
Gate leakage current, forward	I_{GSSF}	V_{GS}=20V, V_{DS}=0V	-	-	100	nA
Gate leakage current, reverse	I_{GSSR}	V_{GS}=-20V, V_{DS}=0V	-	-	-100	nA
Drain-source on-state resistance	$R_{DS(on)}$	V_{GS}=10 V, I_D=1A T_j = 25°C	- -	 0.96	 1.14	 Ω
Dynamic characteristics						
Input capacitance	C_{iss}	V_{DS}= 100V, V_{GS}= 0V,	-	230	-	pF
Output capacitance	C_{oss}	f = 1 MHz	-	9.9	-	
Reverse transfer capacitance	C_{rss}		-	0.8	-	
Turn-on delay time	$t_{d(on)}$	V_{DD} = 300V, I_D = 2A	-	7	-	ns
Rise time	t_r	R_G = 25Ω, V_{GS}=10V	-	7	-	
Turn-off delay time	$t_{d(off)}$		-	34	-	
Fall time	t_f		-	8	-	
Gate charge characteristics						
Gate to source charge	Q_{gs}	V_{DD}=480V, I_D=2A,	-	1.2	-	nC
Gate to drain charge	Q_{gd}	V_{GS}=0 to 10V	-	2.2	-	
Gate charge total	Q_g		-	5.2	-	
Gate plateau voltage	$V_{plateau}$		-	5.2	-	V
Reverse diode characteristics						
Diode forward voltage	V_{SD}	V_{GS}=0 V, I_F=1A	-	-	1.2	V
Reverse recovery time	t_{rr}	V_R=50V, I_F=2A,	-	82	-	ns
Reverse recovery charge	Q_{rr}	dI_F/dt=100A/μs	-	0.4	-	μC
Peak reverse recovery current	I_{rrm}		-	7.5	-	A

Notes:

1. Limited by $T_{j\,max}$. Maximum duty cycle D=0.5.

2. Repetitive rating: pulse width limited by maximum junction temperature.

3. I_{AS} = 0.7A, V_{DD} = 50V, R_G = 25Ω, starting T_j = 25°C.

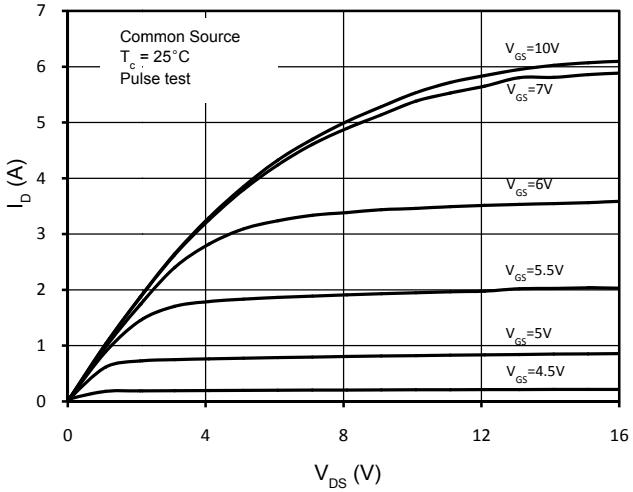


Figure 1.On-Region Characteristics

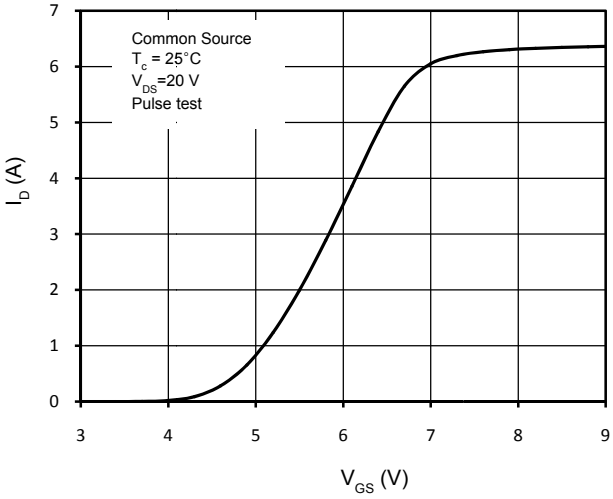


Figure 2. Transfer Characteristics

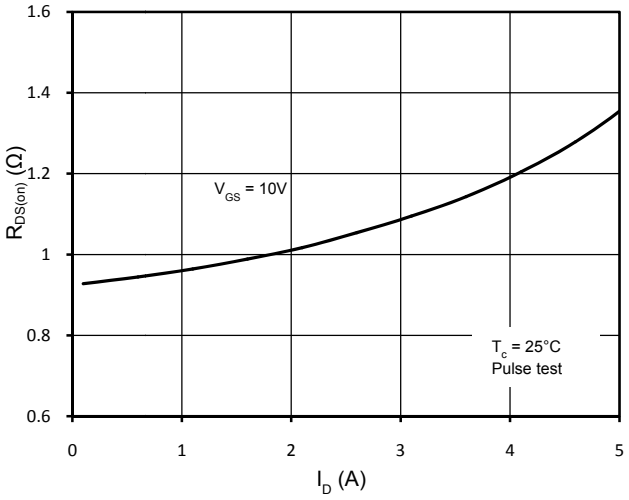


Figure 3. Static Drain-Source On Resistance

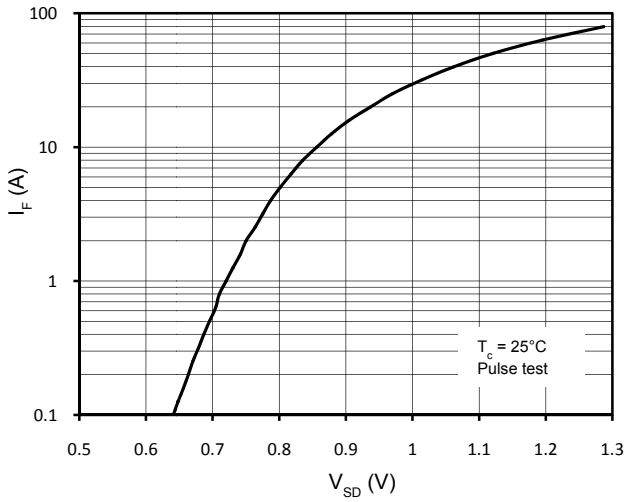


Figure 4. Body- Diode Forward Characteristics

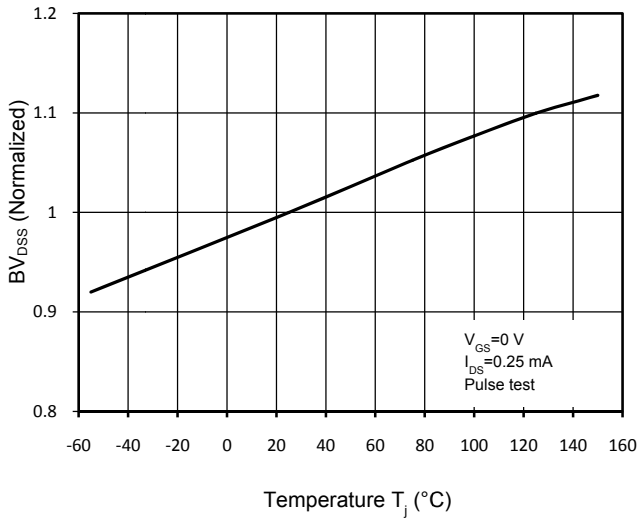


Figure 5. Normalized BV_{DSS} vs. Temperature

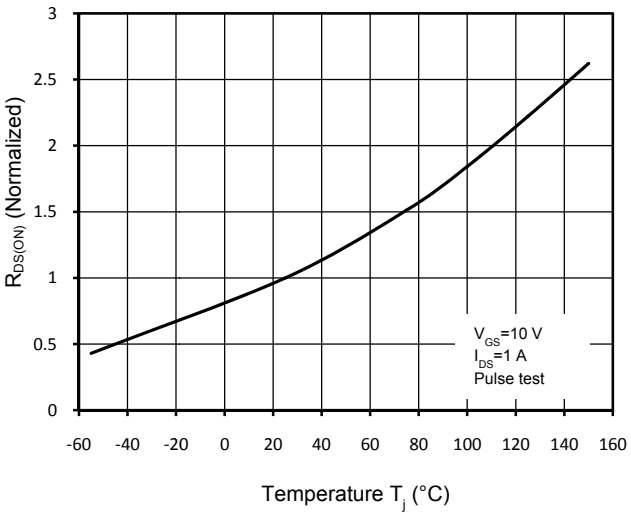


Figure 6. Normalized $R_{DS(on)}$ vs. Temperature

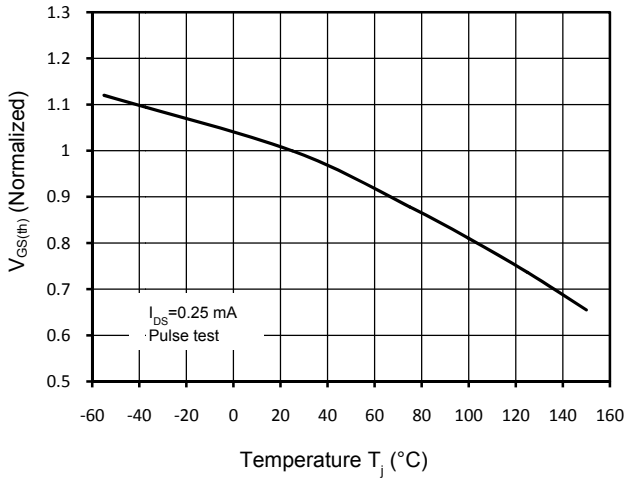


Figure 7. Threshold Voltage vs. Temperature

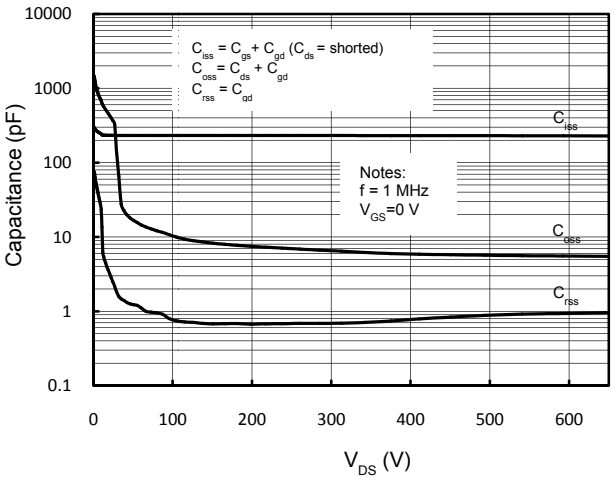


Figure 8. Capacitance Characteristics

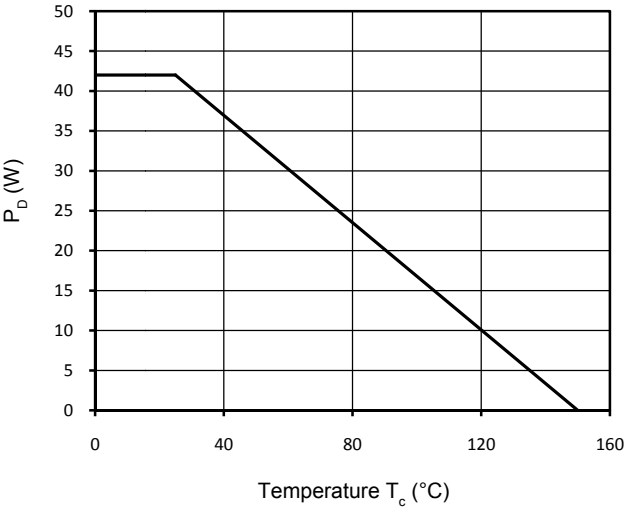


Figure 9. Power Dissipation

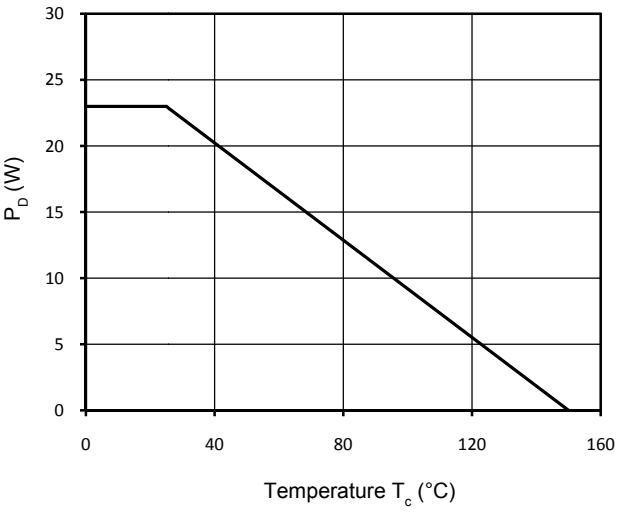


Figure 10. Power Dissipation (TO-220FT)

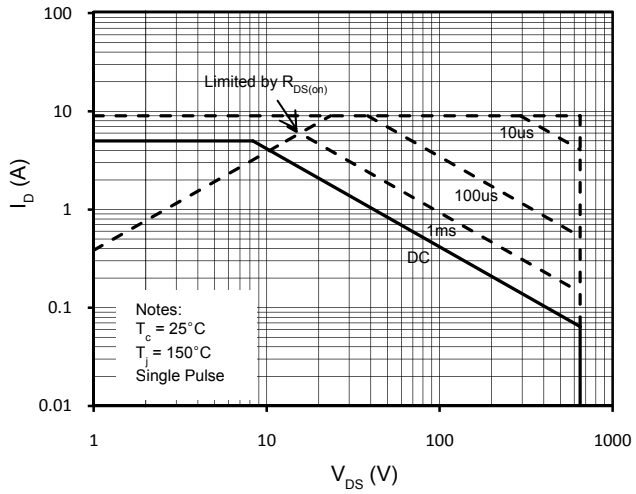


Figure 11. Maximum Safe Operating Area

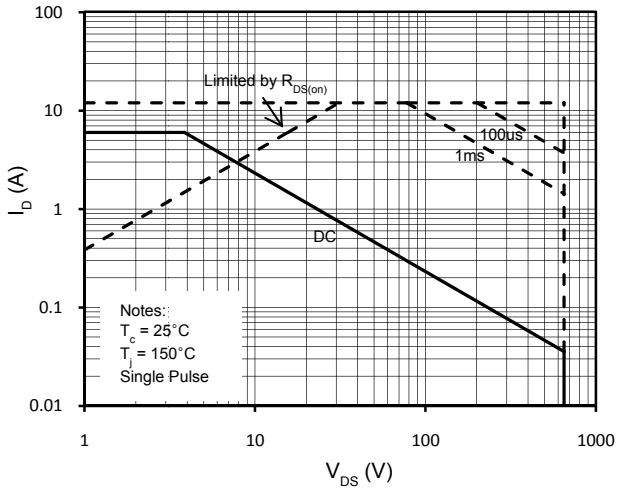


Figure 12. Maximum Safe Operating Area(TO-220FT)

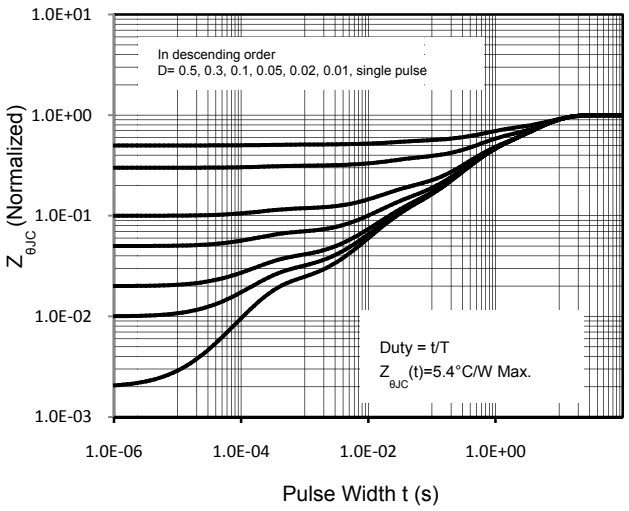


Figure 13. Transient Thermal Response Curve (TO-220FT)

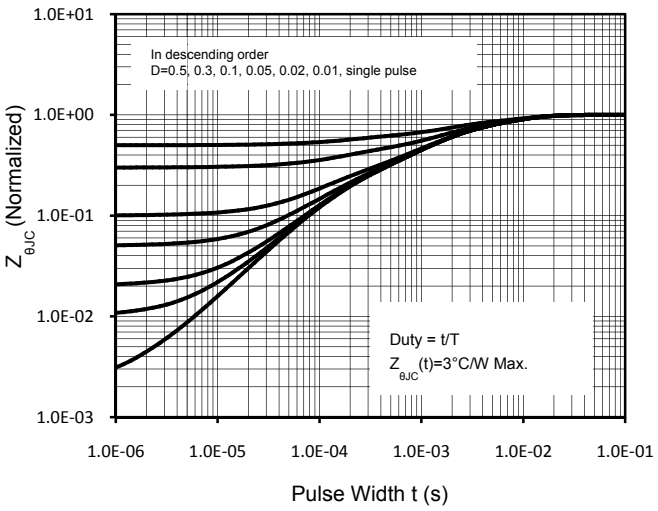


Figure 14. Transient Thermal Response Curve

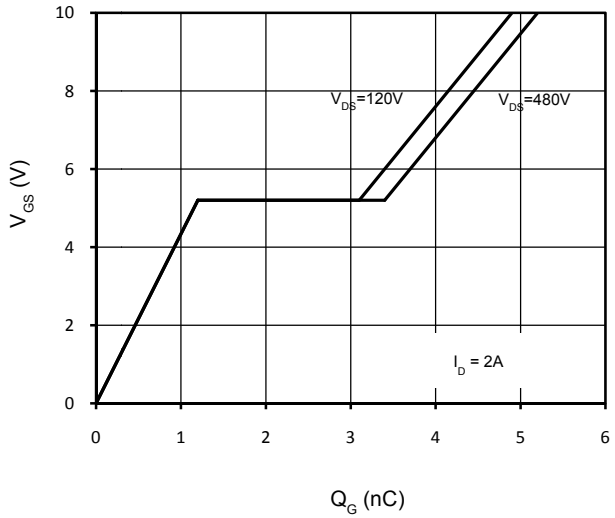
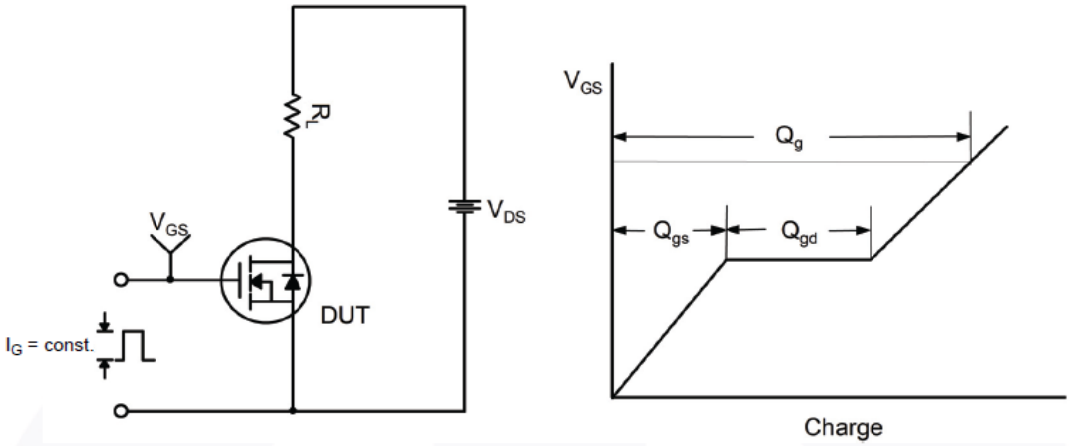
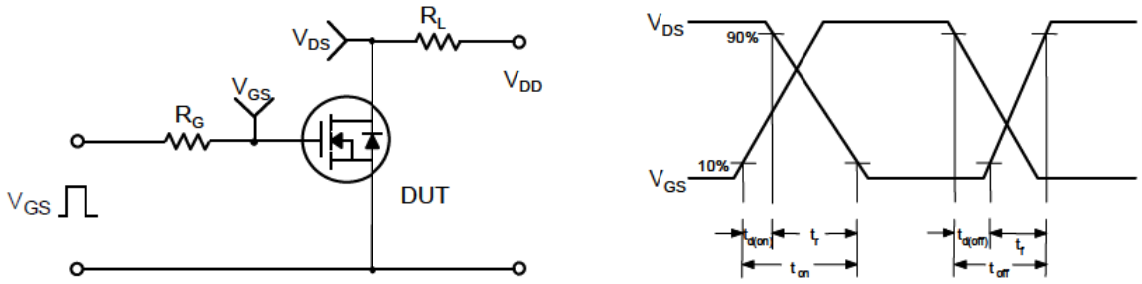


Figure 15. Gate Charge Characteristics

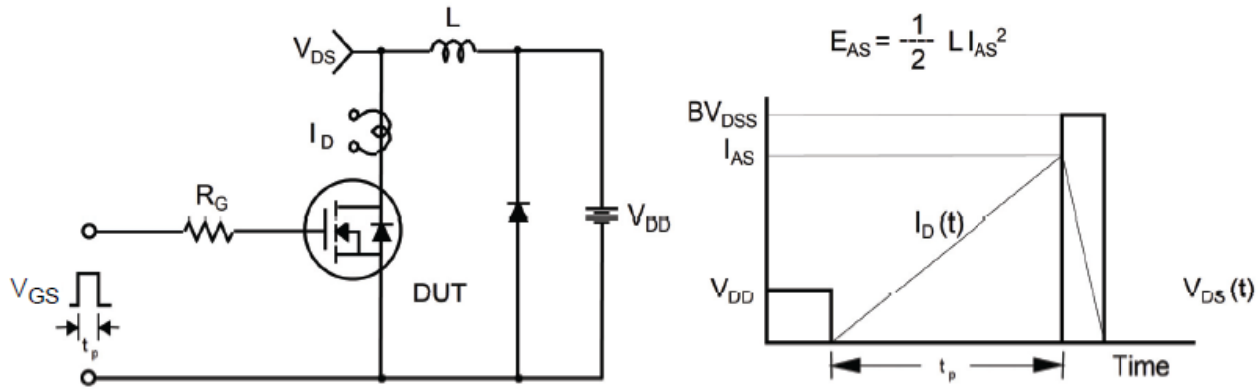
Gate Charge Test Circuit & Waveform



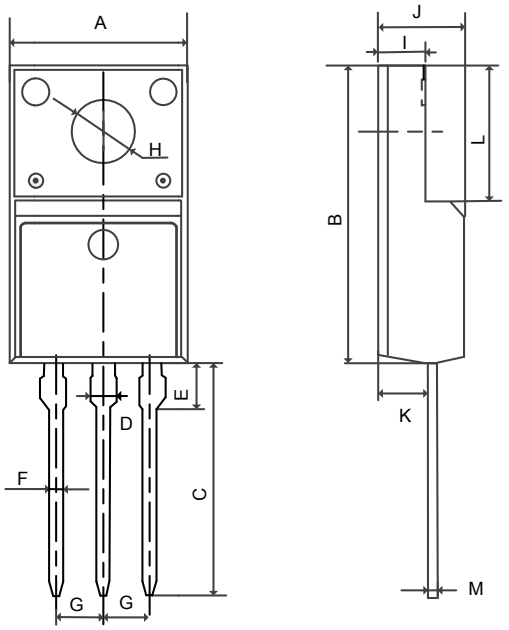
Switching Test Circuit & Waveforms



Unclamped Inductive Switching Test Circuit & Waveforms



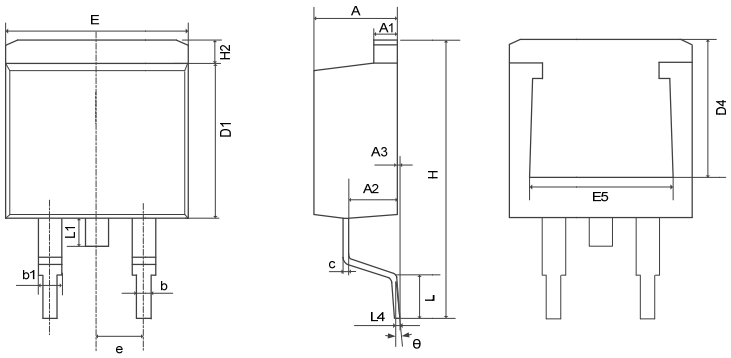
Mechanical Dimensions for TO-220FT



COMMON DIMENSIONS

SYMBOL	MM	
	MIN	MAX
A	9.96	10.36
B	15.67	16.07
C	12.70	13.30
D	1.12	1.32
E	1.85	2.15
F	0.59	0.79
G	2.39	2.69
H	3.08	3.29
I	2.34	2.74
J	4.50	4.90
K	2.61	2.91
L	6.50	6.90
M	0.40	0.60

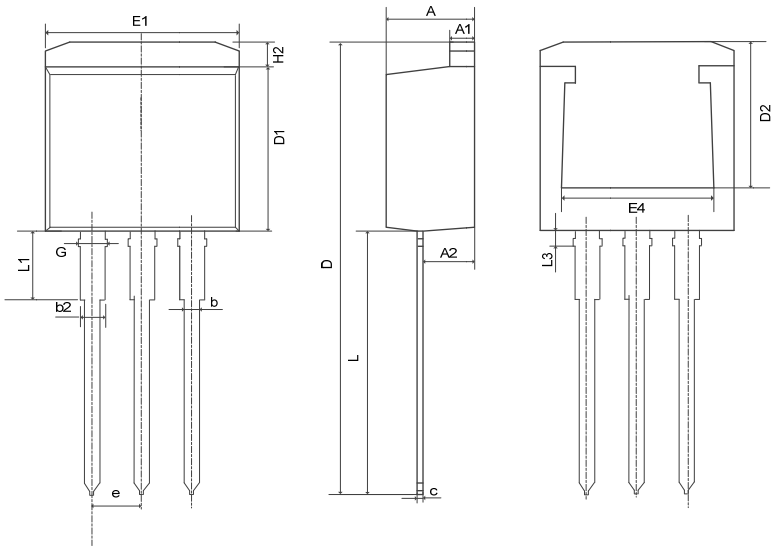
Mechanical Dimensions for TO-263



COMMON DIMENSIONS

SYMBOL	MM	
	MIN	MAX
A	4.37	4.89
A1	1.17	1.42
A2	2.49	2.89
b	0.70	0.96
b1	1.17	1.47
c	0.30	0.53
D1	8.45	8.90
D4	6.60	—
E	9.86	10.40
E5	7.06	—
e	2.54BSC	
H	14.70	15.50
H2	1.07	1.47
L	2.00	2.70
L1	1.40	1.70
L4	0.25BSC	
θ	0°	9°

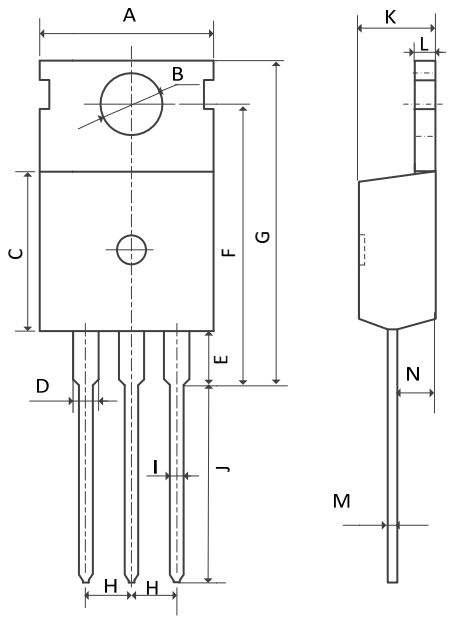
Mechanical Dimensions for TO-262



COMMON DIMENSIONS

SYMBOL	MM	
	MIN	MAX
A	4.37	4.90
A1	1.17	1.42
A2	2.49	2.89
b	0.71	0.96
b2	1.07	1.47
c	0.28	0.53
D	23.20	24.02
D1	8.45	8.90
D2	6.00	—
E1	9.86	10.40
E4	7.06	—
e	2.54BSC	
G	1.25	1.50
H2	—	1.50
L	13.33	14.16
L1	3.50	4.00
L3	1.28	1.58

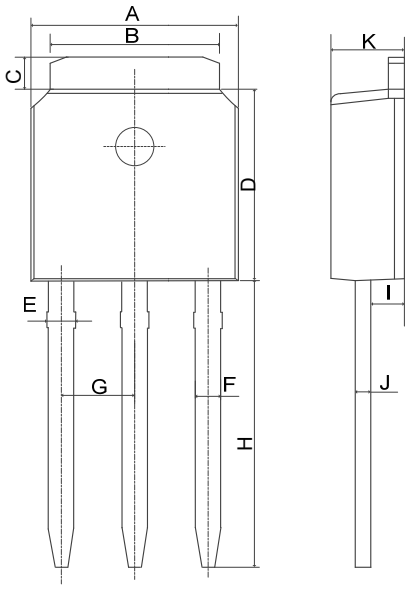
Mechanical Dimensions for TO-220



COMMON DIMENSIONS

SYMBOL	MM	
	MIN	MAX
A	9.70	10.20
B	3.40	3.80
C	8.90	9.40
D	1.17	1.47
E	2.60	3.40
F	15.10	16.70
G	19.55MAX	
H	2.54REF	
I	0.70	0.95
J	9.35	11.00
K	4.30	4.77
L	1.20	1.45
M	0.40	0.65
N	2.20	2.60

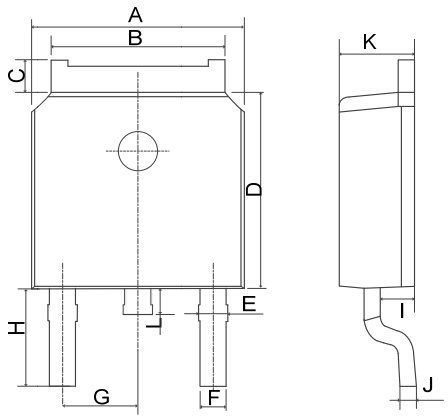
Mechanical Dimensions for TO-251



COMMON DIMENSIONS

SYMBOL	MM	
	MIN	MAX
A	6.40	6.80
B	5.13	5.50
C	0.88	1.28
D	5.90	6.22
E	0.68	1.10
F	0.68	0.91
G	2.29REF	
H	9.00	9.65
I	0.85	1.17
J	0.40	0.61
K	2.10	2.50

Mechanical Dimensions for TO-252



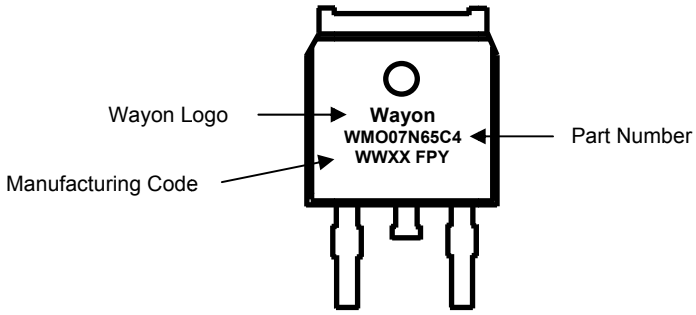
COMMON DIMENSIONS

SYMBOL	MM	
	MIN	MAX
A	6.40	6.80
B	5.13	5.50
C	0.88	1.28
D	5.90	6.22
E	0.68	1.10
F	0.68	0.91
G	2.29REF	
H	2.90REF	
I	0.85	1.17
J	0.51REF	
K	2.10	2.50
L	0.40	1.00

Ordering Information

Part	Package	Marking	Packing method
WML07N65C4	TO-220FT	WML07N65C4	Tube
WMK07N65C4	TO-220	WMK07N65C4	Tube
WMN07N65C4	TO-262	WMN07N65C4	Tube
WMM07N65C4	TO-263	WMM07N65C4	Tape and Reel
WMO07N65C4	TO-252	WMO07N65C4	Tape and Reel
WMP07N65C4	TO-251	WMP07N65C4	Tube

Marking Information



Contact Information

No.1001, Shiwan(7) Road, Pudong District, Shanghai, P.R.China.201202
Tel: 86-21-50310888 Fax: 86-21-50757680 Email: market@way-on.com
WAYON website: **http://www.way-on.com**
For additional information, please contact your local Sales Representative.

Disclaimer

WAYON reserves the right to make changes without further notice to any Products herein to improve reliability, function, or design. The Products are not designed for use in hostile environments, including, without limitation, aircraft, nuclear power generation, medical appliances, and devices or systems in which malfunction of any Product can reasonably be expected to result in a personal injury. The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. WAYON does not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Products or technical information described in this document.